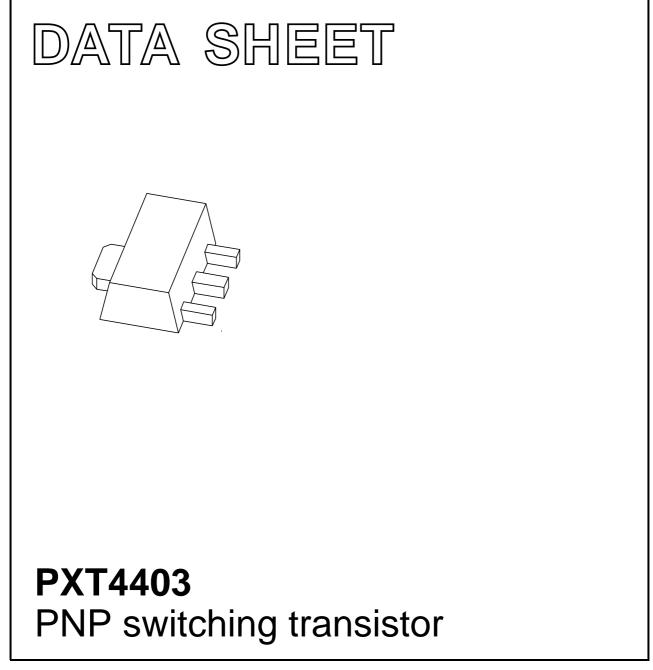
DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 1999 Apr 14 2004 Nov 22



Product data sheet

PNP switching transistor

FEATURES

- High current (max. 600 mA)
- Low voltage (max. 40 V).

APPLICATIONS

• Switching and linear amplification.

DESCRIPTION

PNP switching transistor in a SOT89 plastic package. NPN complement: PXT4401.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾
PXT4403	*2T

Note

- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.

* = W: Made in China.

ORDERING INFORMATION

PINNING

PIN	DESCRIPTION	
1	emitter	
2	collector	
3	base	

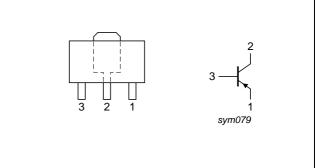


Fig.1 Simplified outline (SOT89) and symbol.

TYPE NUMBER	PACKAGE		
	NAME DESCRIPTION VERS		VERSION
PXT4403	SC-62	SC-62 plastic surface mounted package; collector pad for good heat S transfer; 3 leads	

PXT4403

PXT4403

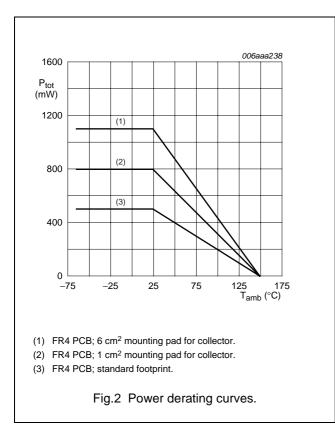
LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	-40	V
V _{CEO}	collector-emitter voltage	open base	-	-40	V
V _{EBO}	emitter-base voltage	open collector	-	-5	V
I _C	collector current (DC)		—	-600	mA
I _{CM}	peak collector current		-	-800	mA
I _{BM}	peak base current		—	-200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
		note 1	—	0.5	W
		note 2	—	0.8	W
		note 3	—	1.1	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

Notes

- 1. Device mounted on a printed-circuit board, single-sided copper, tin-plated and standard footprint.
- 2. Device mounted on a printed-circuit board, single-sided copper, tin-plated and mounting pad for collector 1 cm².
- 3. Device mounted on a printed-circuit board, single-sided copper, tin-plated and mounting pad for collector 6 cm².



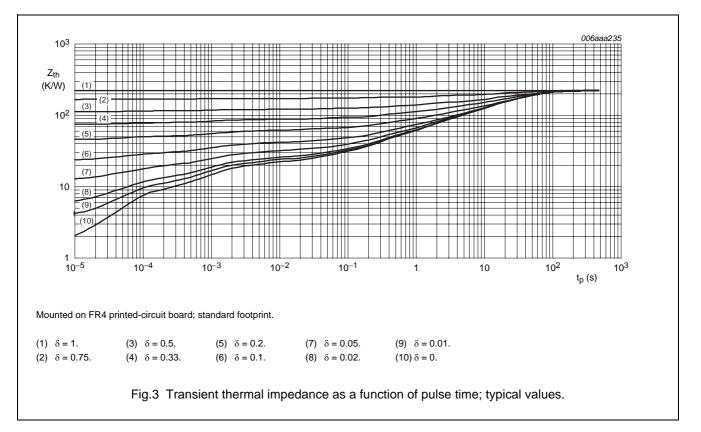
PXT4403

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to	in free air		
	ambient	note 1	250	K/W
		note 2	156	K/W
		note 3	113	K/W
R _{th(j-s)}	thermal resistance from junction to soldering point		30	K/W

Notes

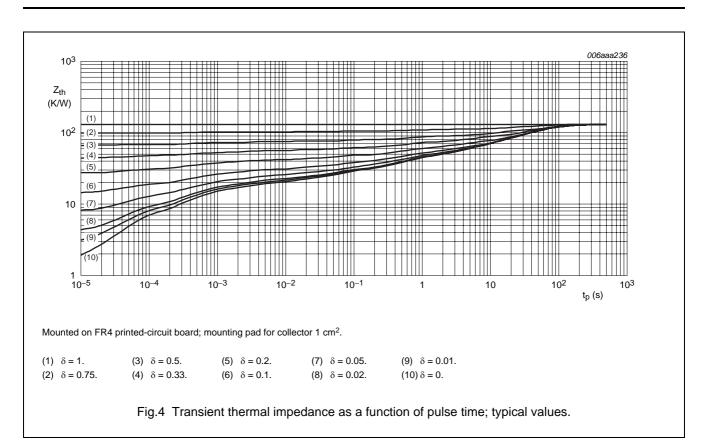
- 1. Device mounted on a printed-circuit board, single-sided copper, tin-plated and standard footprint.
- 2. Device mounted on a printed-circuit board, single-sided copper, tin-plated and mounting pad for collector 1 cm².
- 3. Device mounted on a printed-circuit board, single-sided copper, tin-plated and mounting pad for collector 6 cm².

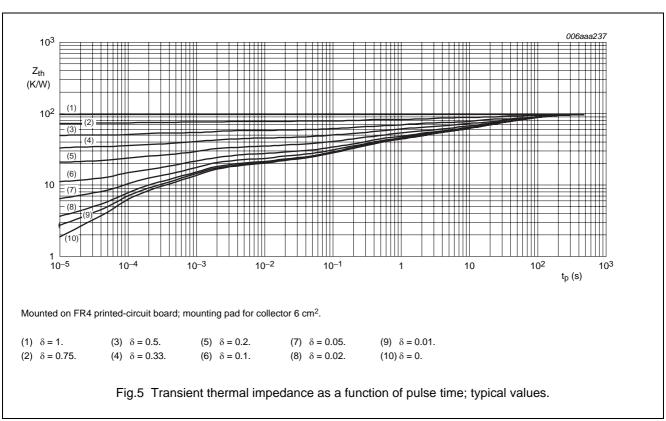


Product data sheet

PNP switching transistor

PXT4403



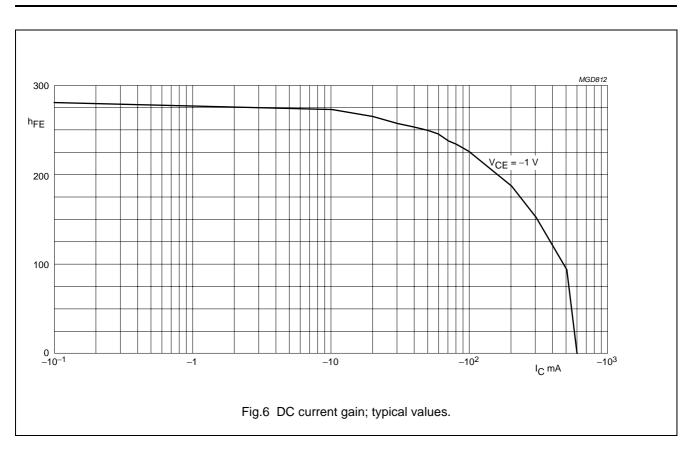


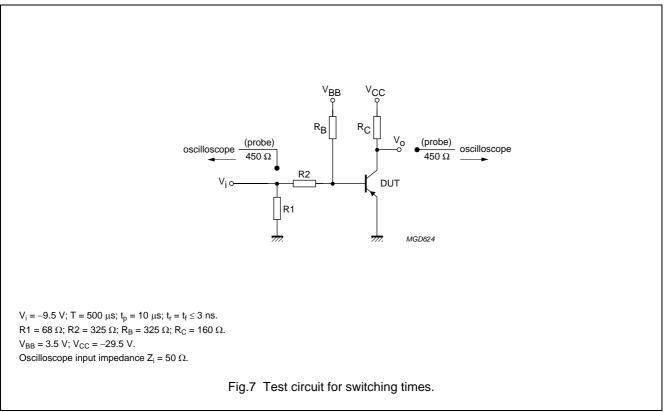
PXT4403

CHARACTERISTICS

T _{amb} = 25 °	C unless	otherwise	specified.
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SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$I_E = 0 \text{ A}; V_{CB} = -40 \text{ V}$	-	-50	nA
I _{EBO}	emitter-base cut-off current	$I_{C} = 0 \text{ A}; V_{EB} = -5 \text{ V}$	-	-50	nA
h _{FE}	DC current gain	$I_{C} = -0.1 \text{ mA}; V_{CE} = -1 \text{ V}$	30	_	
		$I_{C} = -1 \text{ mA}; V_{CE} = -1 \text{ V}$	60	_	
		$I_{C} = -10 \text{ mA}; V_{CE} = -1 \text{ V}$	100	_	
		$I_{\rm C} = -150 \text{ mA}; V_{\rm CE} = -2 \text{ V}$	100	300	
		$I_{\rm C} = -500 \text{ mA}; V_{\rm CE} = -2 \text{ V}$	20	-	
V _{CEsat}	collector-emitter saturation	$I_{\rm C} = -150 \text{ mA}; I_{\rm B} = -15 \text{ mA}$	-	-400	mV
	voltage	$I_{\rm C} = -500 \text{ mA}; I_{\rm B} = -50 \text{ mA}$	-	-750	mV
V _{BEsat}	base-emitter saturation voltage	I _C = -150 mA; I _B = -15 mA	-	-950	mV
		$I_{\rm C} = -500 \text{ mA}; I_{\rm B} = -50 \text{ mA}$	-	-1.3	V
C _c	collector capacitance	$I_E = i_e = 0 \text{ A}; V_{CB} = -10 \text{ V}; \text{ f} = 1 \text{ MHz}$	-	8.5	pF
C _e	emitter capacitance	$I_{C} = i_{c} = 0 \text{ A}; V_{EB} = -500 \text{ mV}; \text{ f} = 1 \text{ MHz}$	-	35	pF
f _T	transition frequency	$I_{C} = -20 \text{ mA}; V_{CE} = -10 \text{ V}; f = 100 \text{ MHz}$	200	-	MHz
Switching t	imes (between 10% and 90% lev	r els) ; (see Fig.7)			
t _{on}	turn-on time	$I_{Con} = -150 \text{ mA}; I_{Bon} = -15 \text{ mA};$	_	40	ns
t _d	delay time	I _{Boff} = 15 mA	_	15	ns
t _r	rise time		_	30	ns
t _{off}	turn-off time]	_	350	ns
t _s	storage time		_	300	ns
t _f	fall time]	_	50	ns

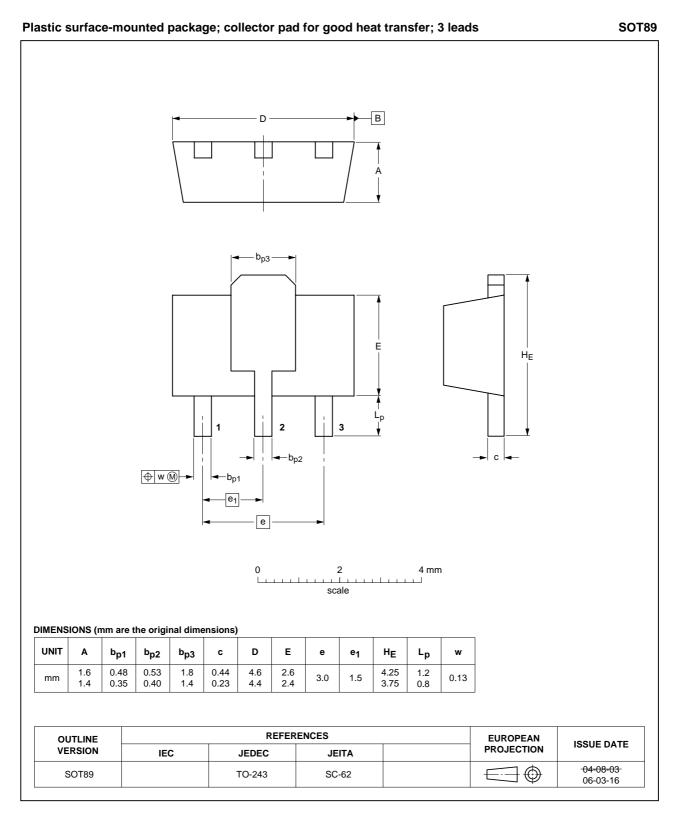




PXT4403

PXT4403

PACKAGE OUTLINE



PXT4403

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

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